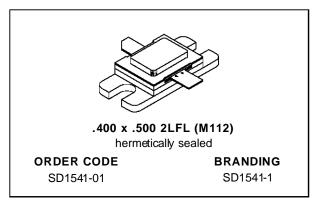


# SD1541-01

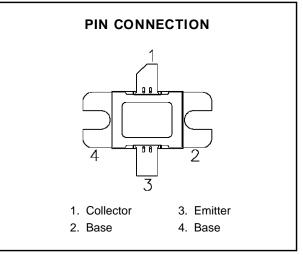
# RF & MICROWAVE TRANSISTORS AVIONICS APPLICATIONS

- DESIGNED FOR HIGH POWER PULSED IFF AND DME APPLICATIONS
- 400 (min.) DME 1025 1150 MHz
- 6.5 dB MIN. GAIN
- REFRACTORY GOLD METALLIZATION
- EMITTER BALLASTING AND LOW THERMAL RESISTANCE FOR RELIABILITY AND RUGGEDNESS
- 30:1 LOAD VSWR CAPABILITY AT SPECIFICIED OPERATING CONDITIONS
- INPUT/OUTPUT MATCHED, COMMON BASE CONFIGURATION



### **DESCRIPTION**

The SD1541-01 is a hermetically sealed, gold metallized, silicon NPN power transistor. The SD1541-01 is designed for applications requiring high peak power and low duty cycles such as DME. The SD1541-01 is packaged in a hermetic metal/ceramic package with internal input/output matching, resulting in improved broadband performance and a low thermal resistance.



# **ABSOLUTE MAXIMUM RATINGS** $(T_{case} = 25^{\circ}C)$

Symbol	Parameter	Unit		
V <sub>CBO</sub>	Collector-Base Voltage	65 V		
V <sub>CES</sub>	Collector-Emitter Voltage	V		
V <sub>EBO</sub>	Emitter-Base Voltage	3.5	V	
lc	Device Current	22	А	
Poiss	Power Dissipation	1458	W	
TJ	Junction Temperature	+200	°C	
T <sub>STG</sub>	Storage Temperature	- 65 to +150	°C	

#### THERMAL DATA

R <sub>TH(j-c)</sub> Junction-Case Thermal Resistance	0.12	°C/W
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# **ELECTRICAL SPECIFICATIONS** (Tcase = 25°C)

#### **STATIC**

Symbol	Test Conditions	Value			Unit		
		Min.	Тур.	Max.			
ВУсво	I <sub>C</sub> = 25mA	$I_E = 0mA$		65	_	_	V
BVces	I <sub>C</sub> = 50mA	V <sub>BE</sub> = 0V		65	_	_	V
BV <sub>EBO</sub>	I <sub>E</sub> = 10mA	$I_C = 0mA$		3.5	_	_	V
I <sub>CES</sub>	V <sub>CE</sub> = 50V	$I_E = 0mA$		_	_	25	mA
hFE	Vce = 5V	Ic = .25A		5	_	200	_

#### **DYNAMIC**

Symbol	Symbol Test Conditions		Value			Unit
Symbol			Min.	Тур.	Max.	Unit
Pout	f = 1025 — 1150MHz P <sub>IN</sub> = 90 W	$V_{CE} = 50 \text{ V}$	400	_	_	W
G <sub>P</sub>	f = 1025 — 1150MHz P <sub>IN</sub> = 90 W	V <sub>CE</sub> = 50 V	6.5	_	_	dB

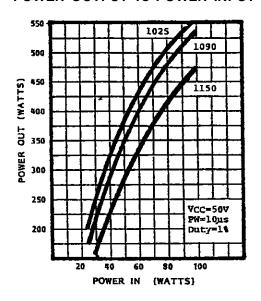
Note: Pulse Width =  $10\mu$ Sec, Duty Cycle = 1%

This device is suitable for use under other pulse width/duty cycle conditions.

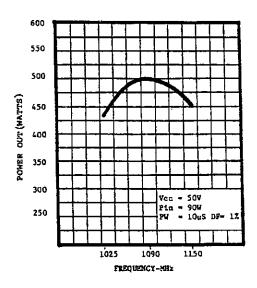
Please contact the factory for specific applications assistance.

#### **TYPICAL PERFORMANCE**

#### POWER OUTPUT vs POWER INPUT



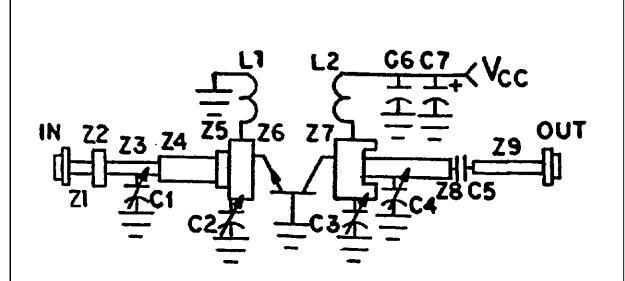
#### **POWER OUTPUT vs FREQUENCY**



#### **IMPEDANCE DATA**

FREQ.	Z <sub>IN</sub> (Ω)	Z <sub>CL</sub> (Ω)		
1020 MHz	2.898 + j 4.1	1.382 – j 3.2		
1090 MHz	2.325 + j 3.4	1.338 – j 2.8		
1150 MHz	1.994 + j 2.8	1.269 – j 2.5		

#### **TEST CIRCUIT**



All Dimensions in Inches Unless Otherwise specified Z3 :  $50\Omega$  .020 x .330; C1 tapped .15 from Load

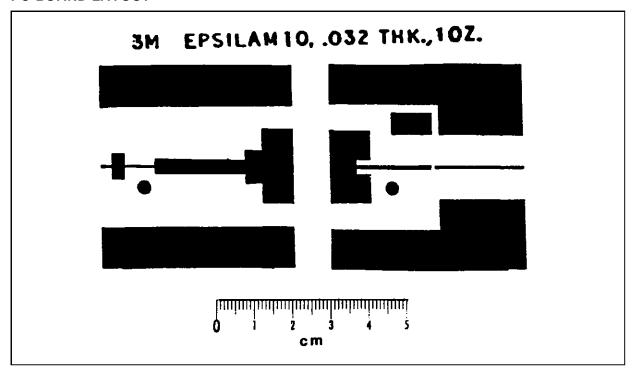
Z4 : .145 x .920 C1 : 0.4 - 2.5pF Johanson Gigatrim Z5 : .325 x .180 C2, C3, Z6 : .730 x .315

L1 : Loop, #18 Tinned, .36 Wide x .27 above Circuit

L2 : 4 3/4 Turns, #24 En., C.W., .075 I.D. C1, C4 : Cold End Terminated Through Eyelet.

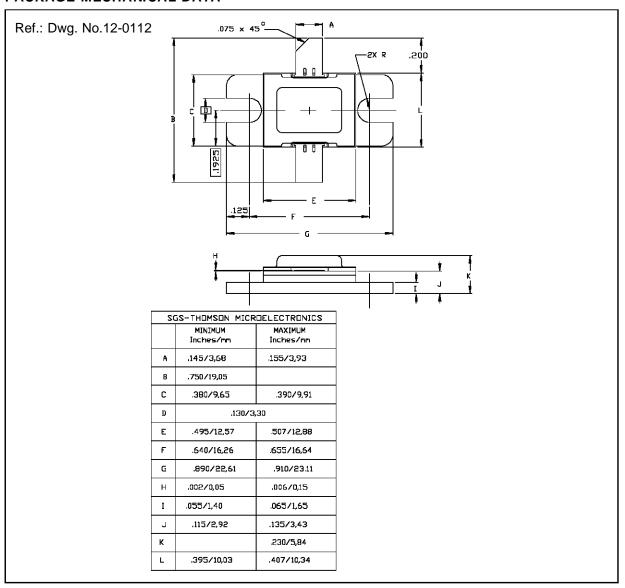
Z1 :  $50\Omega$ (.02 Wide) Z2 : .250 x .120

#### **PC BOARD LAYOUT**



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#### PACKAGE MECHANICAL DATA



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